

SCHOTTKY BARRIER DIODE
Features

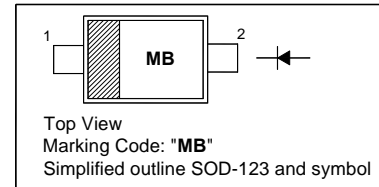
- Low forward voltage

Applications

- Ultra high-speed switching
- Voltage clamping
- Protection circuits

PINNING

PIN	DESCRIPTION
1	Cathode
2	Anode


Absolute Maximum Ratings ($T_a = 25\text{ }^\circ\text{C}$)

Parameter	Symbol	Value	Unit
Reverse Voltage	V_R	30	V
Forward Current	I_F	200	mA
Repetitive Peak Forward Current	I_{FRM}	300	mA
Peak Forward Surge Current ($t_p = 10\text{ ms}$)	I_{FSM}	600	mA
Power Dissipation	P_D	230	mW
Thermal Resistance from Junction Ambient	R_{thJA}	500	K/W
Junction Temperature	T_J	125	$^\circ\text{C}$
Storage Temperature Range	T_{stg}	- 65 to + 150	$^\circ\text{C}$

Characteristics at $T_a = 25\text{ }^\circ\text{C}$

Parameter	Symbol	Max.	Unit
Forward Voltage at $I_F = 0.1\text{ mA}$ at $I_F = 1\text{ mA}$ at $I_F = 10\text{ mA}$ at $I_F = 30\text{ mA}$ at $I_F = 100\text{ mA}$	V_F	240 320 400 500 800	mV
Reverse Current at $V_R = 25\text{ V}$	I_R	2	μA
Total Capacitance at $V_R = 1\text{ V}$, $f = 1\text{ MHz}$	C_T	10	pF
Reverse Recovery Time at $I_F = 10\text{ mA}$, $V_R = 6\text{ V}$, $I_R = 10\text{ mA}$, $R_L = 100\text{ }\Omega$	t_{rr}	6	ns

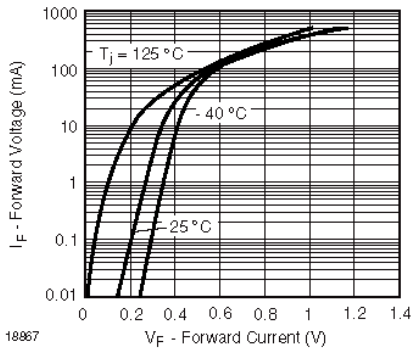


Figure 1. Typical Forward Voltage Forward Current at Various Temperatures

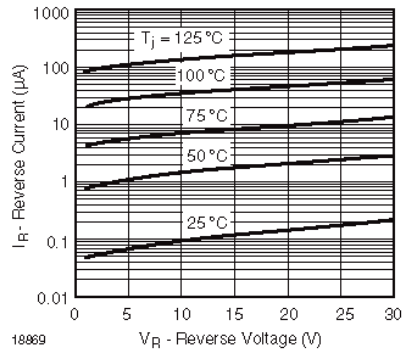


Figure 3. Typical Variation of Reverse Current at Various Temperatures

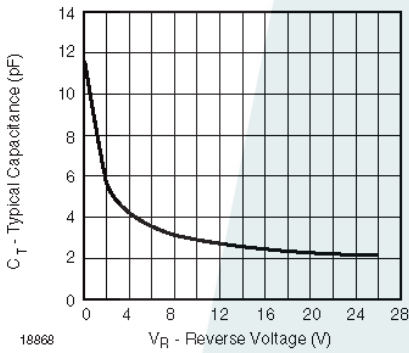


Figure 2. Typical Capacitance vs. Reverse Applied Voltage

PACKAGE OUTLINE

Plastic surface mounted package; 2 leads

SOD-123

